

L Number	Hits	Search Text	DB	Time stamp
13	47	(si or silicon) near2 substrate same gallium adj nitride and nitride near1 device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:38
16	15	(si or silicon) adj substrate same gallium adj nitride and nitride near1 device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:40
19	72	(si or silicon) adj substrate and "III-V" near1 device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 15:17
25	118	"III-V" same (C or carbon) near2 dop\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 16:09
26	28	"III-V" same (oxygen) near2 dop\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 16:31
-	115	buffer near2 (dop\$4 or impurit\$4) and super\$1lattice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 13:39
-	30	buffer near2 (dop\$4 or impurit\$4) same super\$1lattice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 13:46
-	102	"iii-v" same superlattice same (dop\$4 or undop\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 13:48
-	12	"iii-v" same superlattice same (dop\$4 and undop\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 13:56
-	21	"iii-v" same superlattice same nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 14:07
-	4	"iii-v" same nitride near3 buffer same (dop\$4 or undop\$4 or impurit\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 15:25
-	20	nitride near3 buffer same (dop\$4 and undop\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 15:28
-	20	nitride same (dop\$4 and undop\$4) same superlattice	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 15:31